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# FACSIMILE COVER SHEET

Date:	October 15, 2003	Fax:	703-872-9310			
To:	U.S. Patent and Trademark Office	Phone:	703-306-5665			

Technology Center 1700 Fax Center - Before Final

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From:	Carmen C. Cook	BENIRAL FAX CENTER				
Serial No.:	09/902,931	96/ 1/2				
Docket:	M-11706 US (NTG-P101)	1 7 2003				
Re:	Response to Office Action	1				
Pages:	11 (including cover sheet)	<u> </u>				

### Message:

Re:

Applicant(s):

Kirk Martin

Assignce:

Nisene Technology Group

Title:

Method and Apparatus for Etching a Semiconductor Die

Serial No.:

09/902,931

Examiner:

Vinh, Lan

Filed: July 10, 2001

Docket No.:

M-11706 US

Group Art Unit:

1765

(NTG-P101)

## Dear Sir:

Transmitted herewith are the following documents in the above-identified application:

- (1) Transmittal Letter (1 page);
- (2) Response to Office Action (9 pages).

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Brian D. Ogonowsky Carmen C. Cook David C. Hsia Rachel V. Leiterman

October 15, 2003

#### Via Facsimile

Mail Stop Non-Fee Amendment Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

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FFICIAL

CENTRAL FAX CENTER

OCT 16 2003

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No additional fee is required.

The fee has been calculated as shown below:

		Claims Remainin	_	Highest No. Previously Paid For		Present Extra		Rate		Additional <u>Fee</u>
Total	Claims	26	Minus	35	=	0	X	\$9	\$	0.00
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	been considered, an extension of time is hereby requested.  Please charge our Deposit Account No. 502226 in the amount of								0.00	
$\boxtimes$	Also, cl Accoun	narge a <b>ny addit</b> ion t No. 502226.	al fees require	d and credit an	y over	payment	to o	ur Depos	iit	
,							T	otal:	\$	0.00

Certification of Facsimile Transmission

I hereby certify that this paper is being facsimile transmitted to the U.S. Patent and Trademark Office on the date shown below.

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Respectfully submitted,

Carmon C. Cook Attorney for Applicant(s) Reg. No. 42,433

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# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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San Jose, California October 15, 2003

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# RESPONSE TO OFFICE ACTION

Dear Sir:

In response to the Office Action mailed July 30, 2003, Applicant submits the following amendments and remarks.

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 7 of this paper.